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# Contents

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<b>Preface</b> . . . . .	ix
<b>Introduction</b> . . . . .	xiii
<b>Chapter 1. Diodes and Applications</b> . . . . .	1
1.1. Semiconductor physics and current transport in pn diodes . . . . .	1
1.1.1. Energy and concentration of mobile charge carriers (electrons and holes) . . . . .	1
1.1.2. Conduction mechanisms . . . . .	6
1.2. Simplified models of the pn diode . . . . .	9
1.3. Diode circuitry (reviewed in exercises) . . . . .	9
1.4. Detailed model of pn diode: variable conditions and effect of temperature . . . . .	10
1.4.1. Junction at equilibrium (at zero voltage or in open circuit): diffusion potential . . . . .	10
1.4.2. Biased junction (or out of equilibrium): effect of an external potential difference . . . . .	13
1.4.3. Effects of temperature . . . . .	17
1.4.4. Capacitive effects . . . . .	19
1.5. Different types of diode and their functions . . . . .	23
1.5.1. Zener diode . . . . .	23
1.5.2. Schottky diode or metal–semiconductor diode . . . . .	23
1.5.3. Light emitting diodes and laser diodes . . . . .	25
1.5.4. Photodiodes and photovoltaic generators . . . . .	25
1.6. Exercises . . . . .	27
1.6.1. Analyze the operation of the following circuits for a sinusoidal voltage generator and ideal diodes (a) with no threshold and (b) with a threshold $U_0$ . . . . .	27
1.6.2. Study of the current variations in a forward biased pn diode under influence of temperatures . . . . .	30

1.6.3. Analog switch . . . . .	32
1.6.4. Ring modulator . . . . .	35
1.6.5. Switching diode: study on opening . . . . .	37
<b>Chapter 2. Bipolar Junction Transistors and Applications . . . . .</b>	<b>41</b>
2.1. The transistor effect . . . . .	41
2.2. Bipolar junction transistor (or BJT) models and types . . . . .	44
2.2.1. Ebers-Moll model. . . . .	44
2.2.2. The heterojunction bipolar transistor (or HBT) and transistors based on III-V semiconductors . . . . .	48
2.3. Bipolar junction transistor in static regimes and applications of the exponential characteristic $I_C(V_{BE})$ . . . . .	49
2.3.1. Equivalent circuits for the three operating regimes . . . . .	49
2.3.2. Nonlinear applications: differential pairs and multiplier . . . . .	50
2.3.3. Circuits for transistor bias: current sources and current mirrors . . . . .	53
2.3.4. Voltage limitations . . . . .	55
2.4. Small-signal dynamic circuits (linear approximation). . . . .	56
2.4.1. Basic circuits . . . . .	56
2.4.2. Small-signal high-frequency equivalent circuit . . . . .	62
2.5. Power amplification: classes of amplification . . . . .	63
2.6. Bipolar transistor switching on resistive loads . . . . .	65
2.7. Components based on the pnpn structure . . . . .	67
2.7.1. pnpn diode (or Shockley diode) . . . . .	67
2.7.2. Controlled rectifier or thyristor . . . . .	70
2.7.3. Diacs and triacs . . . . .	71
2.8. Phototransistors and optically controlled components. . . . .	73
2.9. Exercises . . . . .	74
2.9.1. Class A amplification . . . . .	74
2.9.2. 4 Quadrant multiplier . . . . .	78
2.9.3. Amplifiers with rest current zero or low relative to nominal current . . . . .	84
2.9.4. Cascode circuit and frequency responses of transistor amplifiers. . . . .	89
<b>Chapter 3. Field Effect Transistors and Applications . . . . .</b>	<b>95</b>
3.1. Operating principle of junction field effect transistors (JFET and MESFET types). . . . .	95
3.2. Metal oxide semiconductor field effect transistors. . . . .	100
3.3. Types of field effect transistors and equivalent circuits . . . . .	104
3.3.1. <i>JFETs, MESFETs and MOSFETs</i> . . . . .	104
3.3.2. Other field effect transistors. . . . .	106

---

3.4. Applications of field effect transistors . . . . .	109
3.4.1. Source of current and JFET biasing . . . . .	109
3.4.2. Amplifiers and mixers . . . . .	110
3.4.3. Variable resistance controlled by the gate-source voltage and JFET analog switch . . . . .	111
3.4.4. Switching circuits and CMOS elementary logic gates (with complementary MOSFET) . . . . .	112
3.4.5. Combinatorial logic functions . . . . .	114
3.4.6. Sequential logic functions. . . . .	126
3.5. Exercises . . . . .	135
3.5.1. Parabolic approximation of the JFET characteristic $I_D(V_{GS})$ in pinched-off (or saturated) regime. . . . .	135
3.5.2. JFET analog switch; input–output insulation in off-state . . . . .	138
3.5.3. MOSFET circuits . . . . .	141
<b>Chapter 4. Amplifiers, Comparators and Other Analog Circuits</b> . . . . .	149
4.1. Operational amplifiers, operating principle and types . . . . .	149
4.1.1. Standard operational amplifiers . . . . .	149
4.1.2. Operational amplifiers with specific properties . . . . .	151
4.2. Operational amplifier models and responses . . . . .	153
4.2.1. Static model of voltage amplifier . . . . .	153
4.2.2. Dynamic and switched mode operations . . . . .	155
4.3. Comparators . . . . .	156
4.4. Noise in amplifiers . . . . .	157
4.4.1. Noise nature and evaluation. . . . .	157
4.4.2. Various types of noise and their origin . . . . .	158
4.4.3. Equivalent circuit of noise sources in amplifiers and noise figure. . . . .	160
4.4.4. Low-noise amplifiers. . . . .	162
4.5. Analog integrated circuits . . . . .	162
4.6. Exercises . . . . .	163
4.6.1. Responses of operational amplifier differential stage. . . . .	163
4.6.2. Generation of triangle and square wave signals: voltage to frequency conversion. . . . .	168
4.6.3. Noise figure of an operational amplifier circuit . . . . .	172
<b>Appendix</b> . . . . .	175
<b>Bibliography</b> . . . . .	187
<b>Index</b> . . . . .	189